## SUPPLEMENTARY INFORMATION

## FOR

## Periodically Spaced CaF<sub>2</sub> Semi-Insulating Thin Ribbons Growth Study on the Si(100) Surface

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**Figure S1**: STM topographies at larger scale of the periodically spaced thin ribbons. (a) set of 7 STM images (93.5 x 93.5 nm, -2.4 V, 15 pA). (b) Zoom in of 3 consecutives STM images (93.5 x 93.5 nm, -2.4 V, 15 pA). (c) Extension of the periodically spaced thin ribbons structure on either side of the central part of the sample. The two STM topographies are acquired with the same conditions (93.5 x 93.5 nm, -2.4 V, 15 pA).



**Figure S2:** Evolution of the dI/dV signal along a thin ribbon for the three considered locations. (a) along the middle of the ribbon. (b) along the edges of the ribbon. (c) aside (or in between) two ribbons.



**Figure S3**: Comparison between dI/dV measurements and DFT PDOS calculations. The dI/dV curves acquired on the thin ribbon are compared with the projected density of states (PDOS) calculated on one of the additional CaF<sub>2</sub> molecule (Ca #3) located along the edge of the thin ribbon. The PDOS curve (orange curve) exhibit two main peaks at energies 2.2 eV and 1.3 eV below the Fermi level. These peaks can be compared to the two dI/dV peaks observed at -1.6 V and -1.9 V.